

TC74LVX174F, TC74LVX174FN, TC74LVX174FT

Hex D-Type Flip-Flop with Clear

The TC74LVX174F/FN/FT is a high-speed CMOS hex D-flip flop fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation. This device is suitable for low voltage and battery operated systems.

Information signals applied to D inputs are transferred to the Q output on the positivegoing edge of the clock pulse. When the CLR input is held low, the Q output are in the low logic level independent of the other inputs.

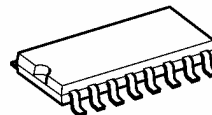
An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

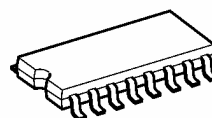
- High-speed: $f_{\max} = 180 \text{ MHz}$ (typ.) ($V_{CC} = 3 \text{ V}$)
- Low power dissipation: $I_{CC} = 4 \mu\text{A}$ (max) ($T_a = 25^\circ\text{C}$)
- Input voltage level: $V_{IL} = 0.8 \text{ V}$ (max) ($V_{CC} = 3 \text{ V}$)
 $V_{IH} = 2.0 \text{ V}$ (min) ($V_{CC} = 3 \text{ V}$)
- Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Low noise: $V_{OLP} = 0.5 \text{ V}$ (max)
- Pin and function compatible with 74HC174

Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74LCX174F

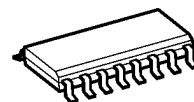


SOP16-P-300-1.27A



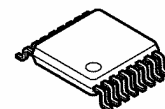
SOP16-P-300-1.27

TC74LCX174FN



SOL16-P-150-1.27

TC74LCX174FT

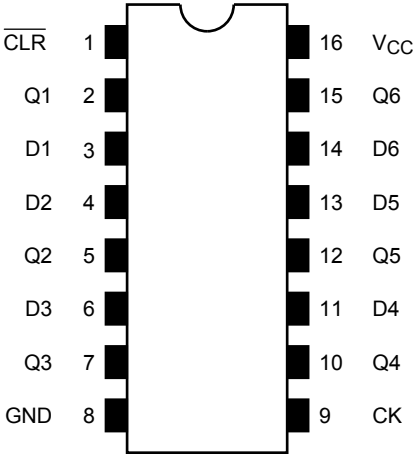


TSSOP16-P-0044-0.65A

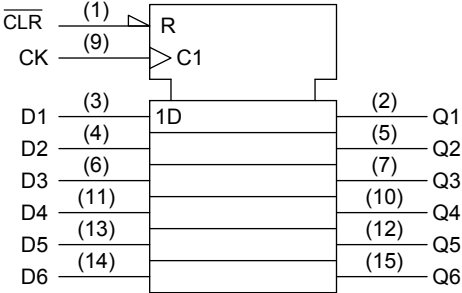
Weight

SOP16-P-300-1.27A	: 0.18 g (typ.)
SOP16-P-300-1.27	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.12 g (typ.)
TSSOP16-P-0044-0.65A	: 0.06 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

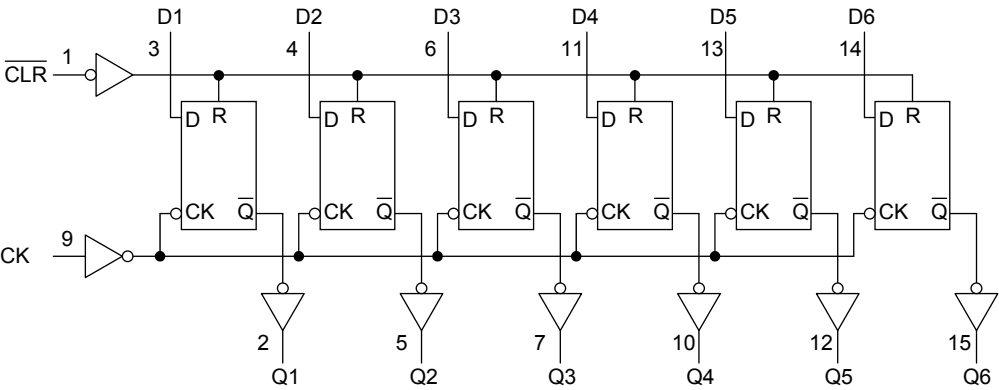


Truth Table

Inputs			Outputs	Function
CLR	D	CK	Q	
L	X	X	L	Clear
H	L		L	—
H	H		H	—
H	X		Qn	No change

X: Don't care

System Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to 7.0	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 3.6	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
					VCC (V)	Min	Typ.	Max	Min		Max
Input voltage	H-level	VIH	—	2.0	1.5	—	—	1.5	—	V	
				3.0	2.0	—	—	2.0	—		
				3.6	2.4	—	—	2.4	—		
	L-level	VIL	—	2.0	—	—	0.5	—	0.5		
				3.0	—	—	0.8	—	0.8		
				3.6	—	—	0.8	—	0.8		
Output voltage	H-level	VOH	VIN = VIH or VIL	IOH = -50 μA	2.0	1.9	2.0	—	1.9	—	V
				IOH = -50 μA	3.0	2.9	3.0	—	2.9	—	
				IOH = -4 mA	3.0	2.58	—	—	2.48	—	
	L-level	VOL	VIN = VIH or VIL	IOL = 50 μA	2.0	—	0.0	0.1	—	0.1	
				IOL = 50 μA	3.0	—	0.0	0.1	—	0.1	
				IOL = 4 mA	3.0	—	—	0.36	—	0.44	
Input leakage current		IIN	VIN = 5.5 V or GND	3.6	—	—	±0.1	—	±1.0	μA	
Quiescent supply current		ICC	VIN = VCC or GND	3.6	—	—	4.0	—	40.0	μA	

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Limit		
Minimum pulse width (CK)	t _W (L)	—	2.7	6.5	7.5	ns
	t _W (H)		3.3 ± 0.3	5.0	5.0	
Minimum pulse width ($\overline{\text{CLR}}$)	t _W (L)	—	2.7	6.5	7.5	ns
			3.3 ± 0.3	5.0	5.0	
Minimum set-up time	t _s	—	2.7	7.5	8.5	ns
			3.3 ± 0.3	5.0	6.0	
Minimum hold time	t _h	—	2.7	0	0	ns
			3.3 ± 0.3	0	0	
Minimum removal time ($\overline{\text{CLR}}$)	t _{rem}	—	2.7	4.5	4.5	ns
			3.3 ± 0.3	3.0	3.0	

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (CK-Q)	t _{pLH}	—	2.7	15	—	7.6	14.5	1.0	17.5	ns
	50			—	10.1	18.0	1.0	21.0		
	t _{pHL}		3.3 ± 0.3	15	—	5.9	9.3	1.0	11.0	
				50	—	8.4	12.8	1.0	14.5	
Propagation delay time ($\overline{\text{CLR}}$ -Q)	t _{pHL}	—	2.7	15	—	7.9	15.0	1.0	18.5	ns
				50	—	10.4	18.5	1.0	22.0	
			3.3 ± 0.3	15	—	6.2	9.7	1.0	11.5	
				50	—	8.7	13.2	1.0	15.0	
Maximum clock frequency	f _{max}	—	2.7	15	65	130	—	55	—	MHz
				50	45	60	—	40	—	
			3.3 ± 0.3	15	115	180	—	95	—	
				50	65	95	—	55	—	
Output to output skew	t _{osLH}	(Note 1)	2.7	50	—	—	1.5	—	1.5	ns
	t _{osHL}		3.3 ± 0.3	50	—	—	1.5	—	1.5	
Input capacitance	C _{IN}	(Note 2)			—	4	10	—	10	pF
Power dissipation capacitance	C _{PD}	(Note 3)			—	29	—	—	—	pF

Note 1: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per F/F)}$$

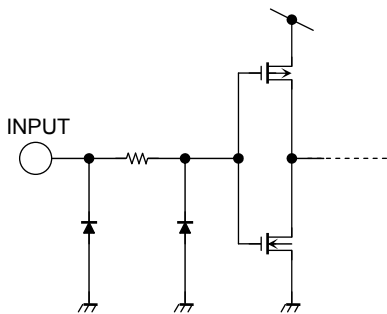
And the total C_{PD} when n pcs. of F/F operate can be gained by the following equation:

$$C_{PD}(\text{total}) = 19 + 10 \cdot n$$

Noise Characteristics (Ta = 25°C, input: tr = tf = 3 ns, CL = 50 pF)

Characteristics	Symbol	Test Condition	VCC (V)	Typ.	Limit	Unit
Quiet output maximum dynamic VOL	VOLP	—	3.3	0.3	0.5	V
Quiet output minimum dynamic VOL	VOLV	—	3.3	−0.3	−0.5	V
Minimum high level dynamic input voltage VIH	VIHD	—	3.3	—	2.0	V
Maximum low level dynamic input voltage VIL	VILD	—	3.3	—	0.8	V

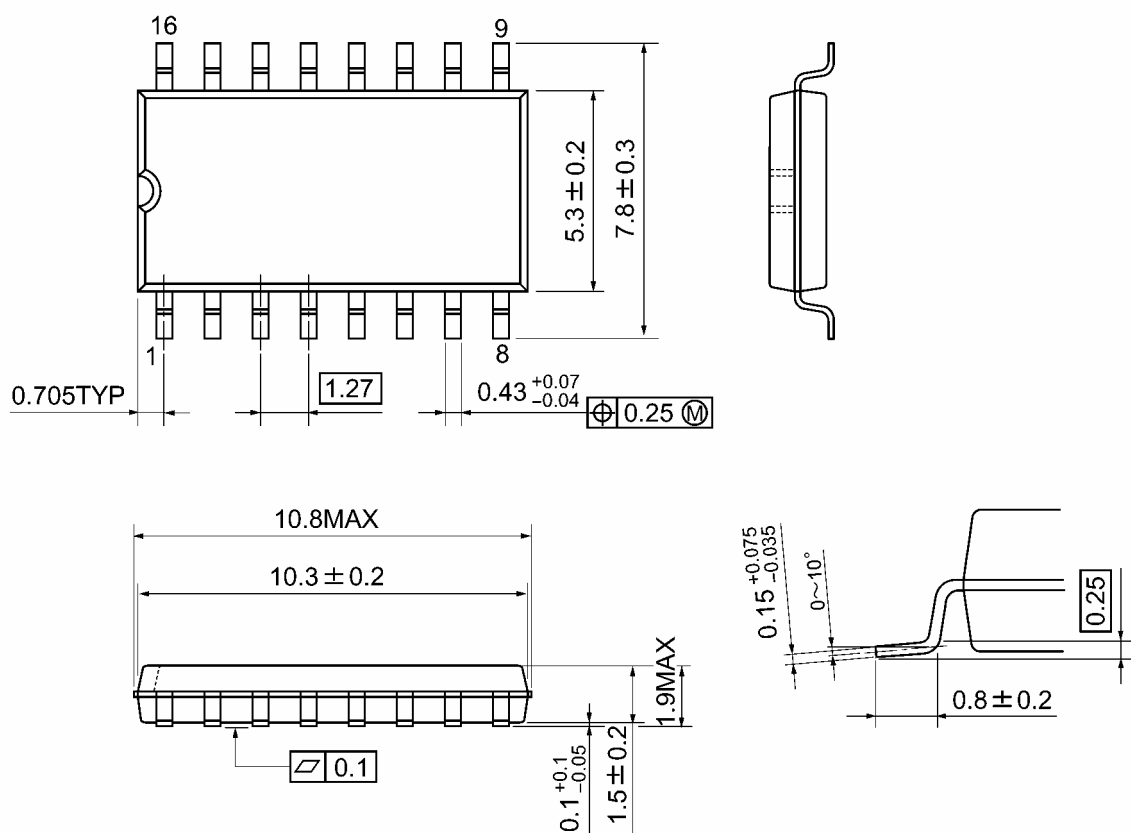
Input Equivalent Circuit



Package Dimensions

SOP16-P-300-1.27A

Unit: mm

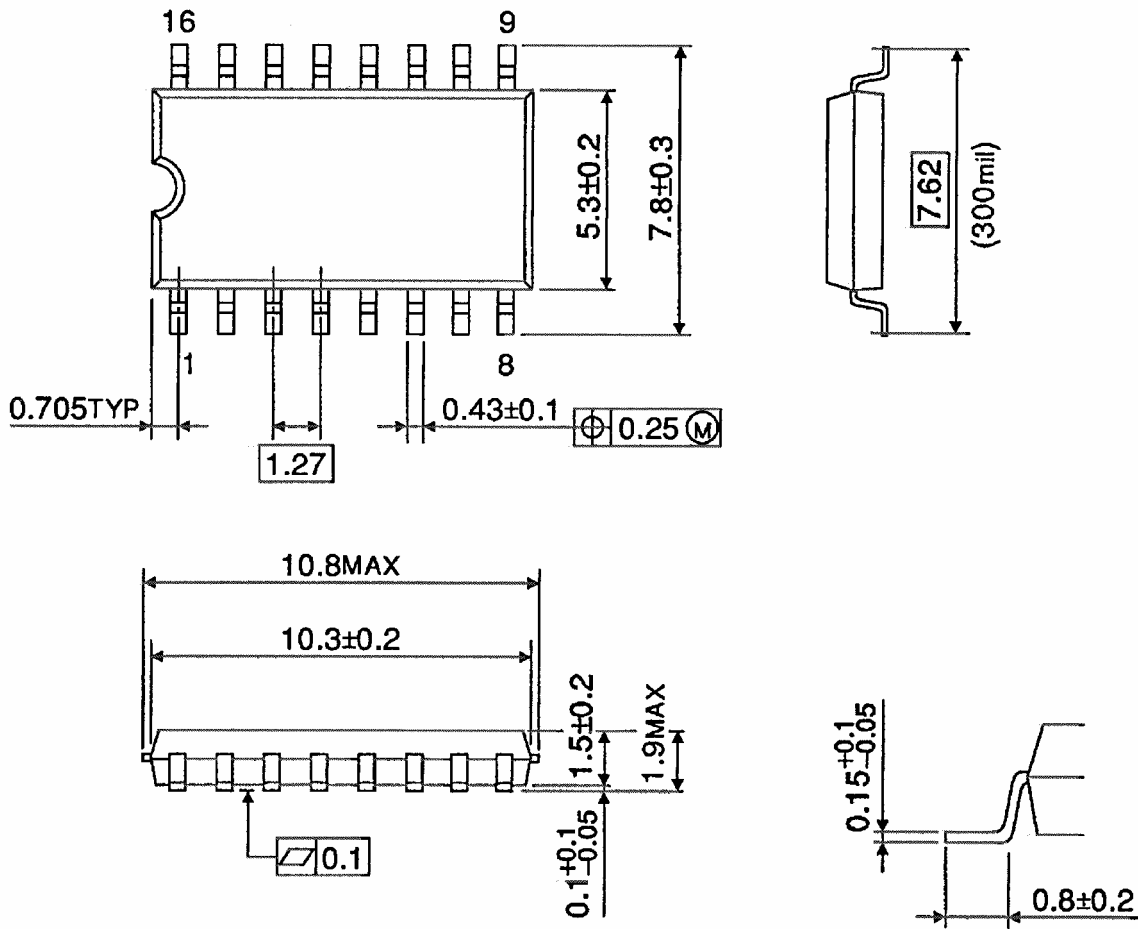


Weight: 0.18 g (typ.)

Package Dimensions

SOP16-P-300-1.27

Unit : mm

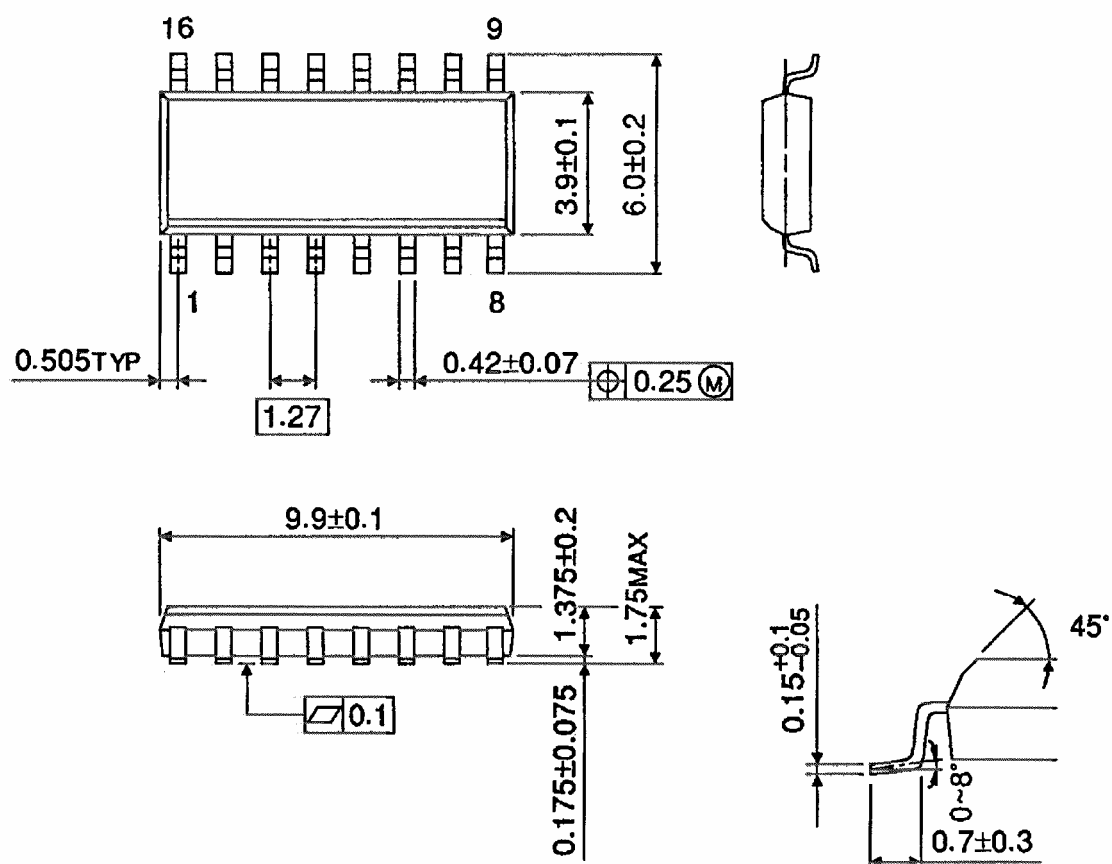


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



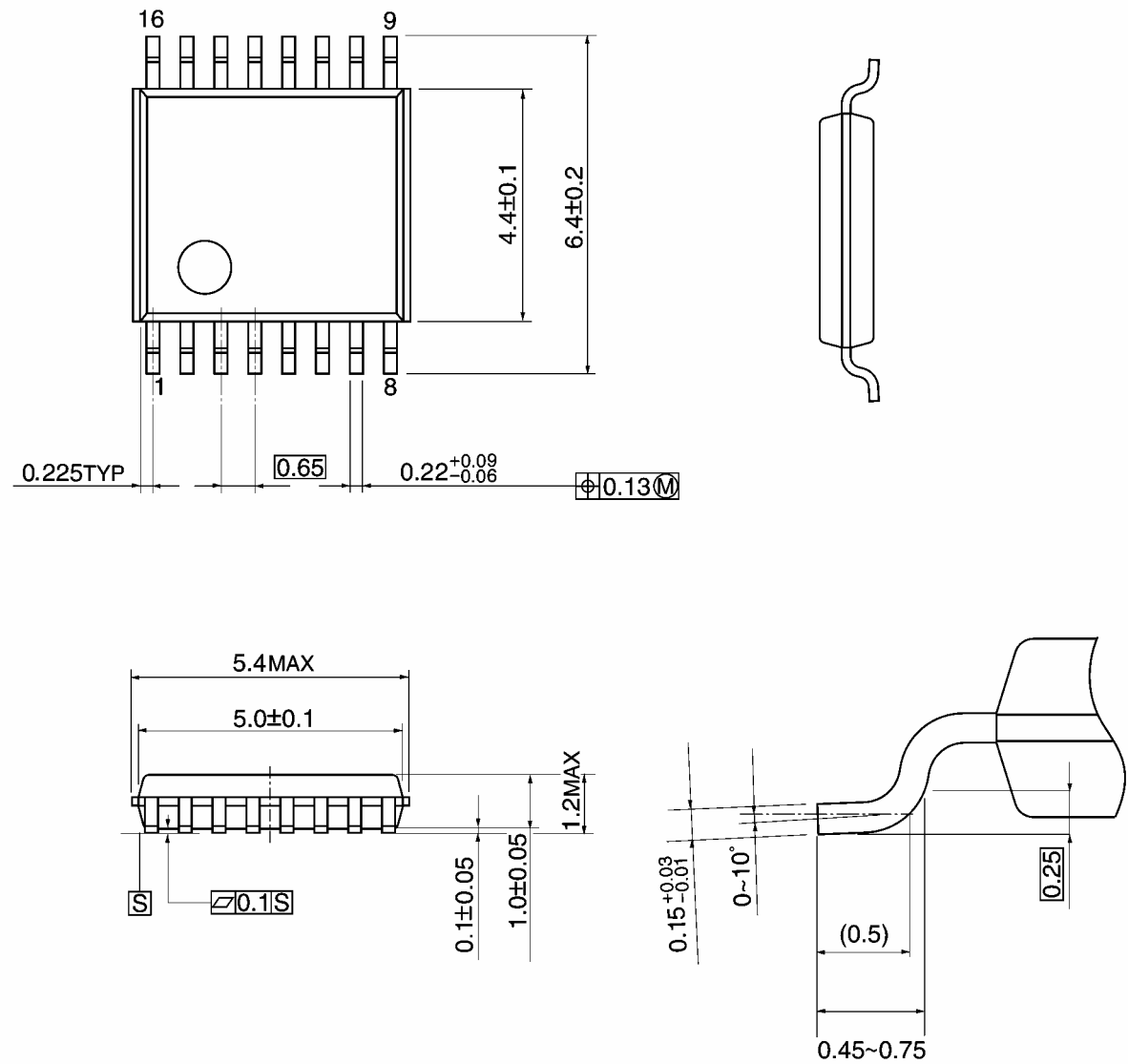
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages**SOP16-P-300-1.27A SOL16-P-150-1.27 TSSOP16-P-0044-0.65A****RESTRICTIONS ON PRODUCT USE**

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